## AMENDMENTS TO THE CLAIMS

This listing of claims will replace all prior versions and listings of claims in the application.

Claim 1. (Original) An internal member of a plasma processing vessel, comprising: a base material; and

a film formed by thermal spraying of ceramic on a surface of the base material,

wherein the film is formed of ceramic including at least one kind of element selected from the group consisting of B, Mg, Al, Si, Ca, Cr, Y, Zr, Ta, Ce and Nd, and at least a portion of the film is sealed by a resin.

Claim 2. (Original) An internal member of a plasma processing vessel, comprising: a base material; and

a film formed by thermal spraying of ceramic on a surface of the base material,

wherein the film has a first ceramic layer formed of ceramic including at least one kind of element selected from the group consisting of B, Mg, Al, Si, Ca, Cr, Y, Zr, Ta, Ce and Nd and a second ceramic layer formed of ceramic including at least one kind of element selected from the group consisting of B, Mg, Al, Si, Ca, Cr, Y, Zr, Ta, Ce and Nd, and at least a portion of at least one of the first and the second ceramic layer is sealed by a resin.

Claim 3. (Currently Amended) The internal member of claim 1, wherein the resin is selected from the group consisting of SI (silicon), PTFE (polytetrafluoroethylene), PI (polyimide), PAI (polyamideimide), PEI (polyetherimide), PBI (polybenzimidazole) and PFA (perfluoroalkoxyalkane).

Claim 4. (Original) The internal member of claim 1, wherein the ceramic is at least one kind of ceramic selected from the group consisting of B<sub>4</sub>C, MgO, Al<sub>2</sub>O<sub>3</sub>, SiC, Si<sub>3</sub>N<sub>4</sub>, SiO<sub>2</sub>, CaF<sub>2</sub>, Cr<sub>2</sub>O<sub>3</sub>, Y<sub>2</sub>O<sub>3</sub>, YF<sub>3</sub>, ZrO<sub>2</sub>, TaO<sub>2</sub>, CeO<sub>2</sub>, Ce<sub>2</sub>O<sub>3</sub>, CeF<sub>3</sub> and Nd<sub>2</sub>O<sub>3</sub>.

Claim 5. (Original) An internal member of a plasma processing vessel, comprising: a base material; and

a film formed by thermal spraying of ceramic on a surface of the base material, wherein the film is formed of ceramic including at least one kind of element selected from the group consisting of B, Mg, Al, Si, Ca, Cr, Y, Zr, Ta, Ce and Nd, and at least a portion of the film is sealed by a sol-gel method.

Claim 6. (Original) An internal member of a plasma processing vessel, comprising: a base material; and

a film formed by thermal spraying of ceramic on a surface of the base material,

wherein the film has a first ceramic layer formed of ceramic including at least one kind of element selected from the group consisting of B, Mg, Al, Si, Ca, Cr, Y, Zr, Ta, Ce and Nd and a second ceramic layer formed of ceramic including at least one kind of element selected from the group consisting of B, Mg, Al, Si, Ca, Cr, Y, Zr, Ta, Ce and Nd, and at least a portion of at least one of the first and the second ceramic layer is sealed by a sol-gel method.

Claim 7. (Currently Amended) The internal member of claim 5, wherein the sealing treatment is executed by using an element of the Group [[3A]] 3a in the periodic table.

Claim 8. (Original) The internal member of claim 5, wherein the ceramic is at least one kind of ceramic selected from the group consisting of B<sub>4</sub>C, MgO, Al<sub>2</sub>O<sub>3</sub>, SiC, Si<sub>3</sub>N<sub>4</sub>, SiO<sub>2</sub>, CaF<sub>2</sub>, Cr<sub>2</sub>O<sub>3</sub>, Y<sub>2</sub>O<sub>3</sub>, YF<sub>3</sub>, ZrO<sub>2</sub>, TaO<sub>2</sub>, CeO<sub>2</sub>, Ce<sub>2</sub>O<sub>3</sub>, CeF<sub>3</sub> and Nd<sub>2</sub>O<sub>3</sub>.

Claim 9. (Original) An internal member of a plasma processing vessel, comprising: a base material; and

a film formed on a surface of the base material,

wherein the film has a main layer formed by thermal spraying of ceramic and a barrier coat layer formed of ceramic including an element selected from the group consisting of B, Mg, Al, Si, Ca, Cr, Y, Zr, Ta, Ce and Nd.

Claim 10. (Original) The internal member of claim 9, wherein the barrier coat layer is formed of at least one kind of ceramic selected from the group consisting of B<sub>4</sub>C, MgO, Al<sub>2</sub>O<sub>3</sub>, SiC, Si<sub>3</sub>N<sub>4</sub>, SiO<sub>2</sub>, CaF<sub>2</sub>, Cr<sub>2</sub>O<sub>3</sub>, Y<sub>2</sub>O<sub>3</sub>, YF<sub>3</sub>, ZrO<sub>2</sub>, TaO<sub>2</sub>, CeO<sub>2</sub>, Ce<sub>2</sub>O<sub>3</sub>, CeF<sub>3</sub> and Nd<sub>2</sub>O<sub>3</sub>.

Claim 11. (Original) The internal member of claim 9, wherein the barrier coat layer is a thermally sprayed film at least a portion of which is sealed by a resin.

Claim 12. (Currently Amended) The internal member of claim 11, wherein the resin is selected from the group consisting of SI (silicon), PTFE (polytetrafluoroethylene), PI (polyimide), PAI (polyamideimide), PEI (polyetherimide), PBI (polybenzimidazole) and PFA (perfluoroalkoxyalkane).

Claim 13. (Original) The internal member of claim 9, wherein the barrier coat layer is a thermally sprayed film at least a portion of which is sealed by a sol-gel method.

Claim 14. (Original) The internal member of claim 13, wherein the sealing treatment is executed by using an element of the Group 3a in the periodic table.

Claim15. (Original) The internal member of claim 9, wherein the main layer is formed of at least one kind of ceramic selected from the group consisting of B<sub>4</sub>C, MgO, Al<sub>2</sub>O<sub>3</sub>, SiC, Si<sub>3</sub>N<sub>4</sub>, SiO<sub>2</sub>, CaF<sub>2</sub>, Cr<sub>2</sub>O<sub>3</sub>, Y<sub>2</sub>O<sub>3</sub>, YF<sub>3</sub>, ZrO<sub>2</sub>, TaO<sub>2</sub>, CeO<sub>2</sub>, Ce<sub>2</sub>O<sub>3</sub>, CeF<sub>3</sub> and Nd<sub>2</sub>O<sub>3</sub>.

Claim 16. (Original) An internal member of a plasma processing vessel, comprising: a base material; and

a film formed on a surface of the base material,

wherein the film has a main layer formed by thermal spraying of ceramic and a barrier coat layer formed of engineering plastic formed between the base material and the main layer.

Claim 17. (Currently Amended) The internal member of claim 16, wherein the engineering plastic is selected from the group consisting of PTFE (polytetrafluoroethylene), PI (polyimide), PAI (polyamideimide), PEI (polyetherimide), PBI (polybenzimidazole), PFA (perfluoroalkoxyalkane), PPS (polyphenylenesulfide) and POM (polyacetal).

Claim 18. (Original) The internal member of claim 16, wherein the main layer is formed of at least one kind of ceramic selected from the group consisting of B<sub>4</sub>C, MgO, Al<sub>2</sub>O<sub>3</sub>, SiC, Si<sub>3</sub>N<sub>4</sub>, SiO<sub>2</sub>, CaF<sub>2</sub>, Cr<sub>2</sub>O<sub>3</sub>, Y<sub>2</sub>O<sub>3</sub>, YF<sub>3</sub>, ZrO<sub>2</sub>, TaO<sub>2</sub>, CeO<sub>2</sub>, Ce<sub>2</sub>O<sub>3</sub>, CeF<sub>3</sub> and Nd<sub>2</sub>O<sub>3</sub>.

Claim 19. (Original) An internal member of a plasma processing vessel, comprising: a base material; and

a film formed on a surface of the base material,

wherein the film is formed of ceramic including at least one kind of element of the Group 3a in the periodic table and at least a portion of the film is hydrated by vapor or high temperature hot water.

Claim 20. (Original) An internal member of a plasma processing vessel, comprising: a base material; and

a film formed on a surface of the base material,

wherein the film has a first ceramic layer formed of ceramic including at least one kind of element of the Group 3a in the periodic table and a second ceramic layer made of ceramic including at least one kind of element of the Group 3a in the periodic table, and at least a portion of at least one of the first and the second ceramic layer is hydrated by vapor or high temperature hot water.

Claim 21. (Original) The internal member of claim 19, wherein the film is a thermally sprayed film formed by thermal spraying or a thin film formed by employing a technique for forming a thin film.

Claim 22. (Original) The internal member of claim 19, wherein the film is formed of ceramic selected from Y<sub>2</sub>O<sub>3</sub>, CeO<sub>2</sub>, Ce<sub>2</sub>O<sub>3</sub> and Nd<sub>2</sub>O<sub>3</sub>.

Claim 23. (Original) An internal member of a plasma processing vessel, comprising: a base material; and

a film formed on a surface of the base material,

wherein the film has a first ceramic layer formed of ceramic including at least one kind of element of the Group 3a in the periodic table and a second ceramic layer formed by thermal spraying of ceramic, and at least a portion of the first ceramic layer is hydrated by vapor or high temperature hot water.

Claim 24. (Original) The internal member of claim 23, wherein the first ceramic layer is a thermally sprayed film formed by thermal spraying or a thin film formed by employing a technique for forming a thin-film.

Claim 25. (Original) The internal member of claim 23, wherein the first ceramic layer is formed of ceramic selected from Y<sub>2</sub>O<sub>3</sub>, CeO<sub>2</sub>, Ce<sub>2</sub>O<sub>3</sub> and Nd<sub>2</sub>O<sub>3</sub>.

Claim 26. (Original) The internal member of claim 23, wherein the second ceramic layer is formed of at least one kind of ceramic selected from the group consisting of B<sub>4</sub>C, MgO, Al<sub>2</sub>O<sub>3</sub>, SiC, Si<sub>3</sub>N<sub>4</sub>, SiO<sub>2</sub>, CaF<sub>2</sub>, Cr<sub>2</sub>O<sub>3</sub>, Y<sub>2</sub>O<sub>3</sub>, YF<sub>3</sub>, ZrO<sub>2</sub>, TaO<sub>2</sub>, CeO<sub>2</sub>, Ce<sub>2</sub>O<sub>3</sub>, CeF<sub>3</sub> and Nd<sub>2</sub>O<sub>3</sub>.

Claim 27. (Original) An internal member of a plasma processing vessel, comprising:

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a base material; and

a film formed on a surface of the base material,

wherein the film has a hydroxide layer formed of hydroxide including at least one kind of element of the Group 3a in the periodic table.

Claim 28. (Original) The internal member of claim 27, wherein the hydroxide layer is a thermally sprayed film formed by thermal spraying or a thin film formed by employing a technique for forming a thin film.

Claim 29. (Original) The internal member of claim 27, wherein the hydroxide forming the hydroxide layer is formed of hydroxide selected from Y(OH)<sub>3</sub>, Ce(OH)<sub>3</sub> and Nd(OH)<sub>3</sub>.

Claim 30. (Original) The internal member of claim 27, wherein at least a portion of the hydroxide layer is sealed.

Claim 31. (Original) The internal member of any one of claims 1, 5, 9, 16, 19, 23 and 27, wherein an anodic oxidized film is formed between the base material and the film.

Claim 32. (Original) The internal member of claim 31, wherein the anodic oxidized film is sealed by an aqueous solution of metal salt.

Claim 33. (Currently Amended) The internal member of claim 31, wherein the anodic oxidized film is sealed by a resin selected from the group consisting of SI (silicon), PTFE (polytetrafluoroethylene), PI (polyimide), PAI (polyamideimide), PEI (polyetherimide), PBI (polybenzimidazole) and PFA (perfluoroalkoxyalkane).

Claim 34. (Original) An internal member of a plasma processing vessel, comprising:

a sintered ceramic body including at least one kind of element of the Group 3a in the periodic table,

wherein at least a portion of the sintered ceramic body is hydrated by vapor or high temperature hot water.

Claim 35. (Currently Amended) The internal member of claim [[33]] 34, wherein the sintered ceramic body is formed by hydrating of ceramic selected from Y<sub>2</sub>O<sub>3</sub>, CeO<sub>2</sub>, Ce<sub>2</sub>O<sub>3</sub> and Nd<sub>2</sub>O<sub>3</sub>.

Claim 36. (Original) An internal member of a plasma processing vessel, comprising: a sintered ceramic body including hydroxide including at least one kind of element of the Group 3a in the periodic table.

Claim 37. (Original) The internal member of claim 36, wherein the sintered ceramic body includes hydroxide selected from Y(OH)<sub>3</sub>, Ce(OH)<sub>3</sub> and Nd(OH)<sub>3</sub>.